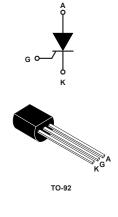


0.8 A 400 V high immunity sensitive SCR thyristor in TO-92





Features

- On-state rms current, I_{T(RMS)} 0.8 A
- 125 °C max. T_i
- Low 0.2 mA gate current
- Repetitive peak off-state voltage, V_{DRM/VRRM} 400 V
- **ECOPACK2** compliant

Applications

- Gate driver for large Thyristors
- Overvoltage crowbar protection
- Ground fault circuit interrupters
- Arc fault circuit interrupter
- Standby mode power supplies
- Residual current detector

Description

Thanks to highly sensitive triggering levels, the 0.8 A P0102DA SCR thyristor is suitable for all applications where available gate current is limited.

This device offers a high blocking voltage of 400 V, ideal for applications like interrupters circuits.

The P0102DA is available in through-hole TO-92 package.

Product status link
P0102DA
1 0102DA

Product summary				
I _{T(RMS)}	0.8 A			
V _{DRM} /V _{RRM}	400 V			
I _{GT}	0.2 mA			
T _j max.	125 °C			



1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameters	Value	Unit		
I _{T(RMS)}	On-state RMS current (180° conduction angle)				Α
I _{T(AV)}	Average on-state current (180° conduction angle))	T _L = 55 °C	0.5	Α
	Non repetitive surge peak on-state current,	t _p = 8.3 ms	T = 25 °C	8	А
I _{TSM}	T _j initial = 25 °C	t _p = 10 ms	T _j = 25 °C	7	
l ² t	I ² t value for fusing	T _j = 25 °C	0.24	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$ $F = 60 \text{ Hz}$ $T_j = 25 ^{\circ}\text{C}$			50	A/µs
V _{DRM} / V _{RRM}	Repetitive peak off-state voltage	400	V		
I _{GM}	Peak gate current $t_p = 20 \mu s$ $T_j = 125 °C$		1	Α	
P _{G(AV)}	Average gate power dissipation	0.1	W		
T _{stg}	Storage junction temperature range	-40 to +150	°C		
T _j	Operating junction temperature range				°C

Table 2. Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Parameters		Value	Unit
I _{GT}	$V_D = 12 \text{ V}, R_I = 33 \Omega$		200	μA
V _{GT}	VD = 12 V, NL = 33 12	Max.	0.8	V
V _{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, R_{GK} = 1 \text{ k}\Omega, T_j = 125 \text{ °C}$	Min.	0.1	V
V _{RG}	I _{RG} = 10 μA	Min.	8	
lн	I_T = 50 mA, R_{GK} = 1 k Ω	Max.	5	mA
IL	$I_G = 1.2 I_{GT}$, $R_{GK} = 1 k\Omega$	Max.	6	mA
dV/dt	$V_D = 67 \% V_{DRM}, R_{GK} = 1 k\Omega, T_j = 125 °C$	Min.	75	V/µs

Table 3. Static electrical characteristics

Symbol	Test conditions	Tj		Value	Unit
V _T	$I_{TM} = 1.6 \text{ A}, t_p = 380 \mu\text{s}$		Max.	1.95	V
V _{TO}	Threshold on-state voltage	125 °C	Max.	0.95	V
R _d	Dynamic resistance		Max.	600	mΩ
I _{DRM}	$V_D = V_{DRM}$	25 °C	Max.	1	μΑ
I _{RRM}	$V_R = V_{RRM}$ 125 °C		0.1	mA	

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Table 4. Thermal resistance

Symbol	Parameters Parameters Parameters	Max. value	Unit
R _{th(j-l)}	Junction to lead (DC)	80	°C/W
R _{th(j-a)}	Junction to ambient (DC)	150	C/VV

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1.1 Characteristics (curves)

Figure 1. Maximum power dissipation versus on-state RMS current (full cycle)

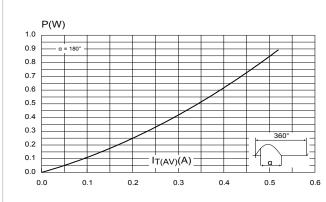


Figure 2. Average and DC on-state current versus lead temperature

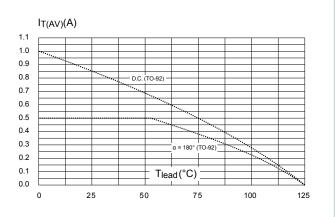


Figure 3. Average and DC on-state current versus ambient temperature

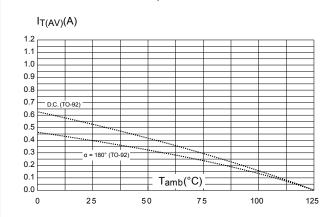


Figure 4. Relative variation of thermal impedance versus pulse duration

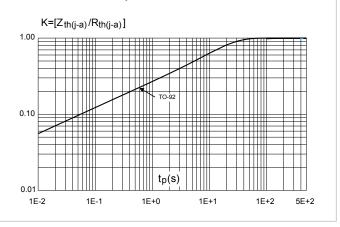


Figure 5. Relative variation of holding current versus gate-cathode resistance

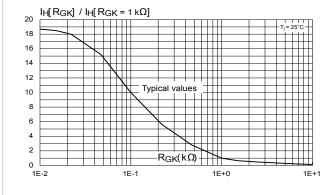
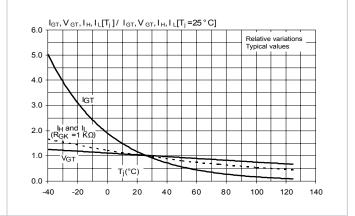


Figure 6. Relative variation of gate voltage and gate, holding and latching current versus junction temperature



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Figure 7. Relative variation of static dV/dt immunity versus gate-cathode resistance

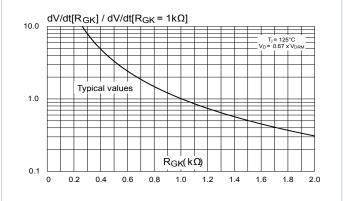


Figure 8. Relative variation of dV/dt immunity versus gatecathode capacitance

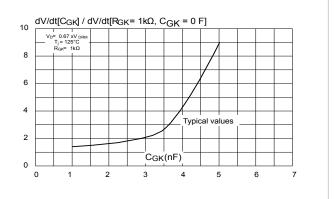


Figure 9. Surge peak on-state current versus number of cycles

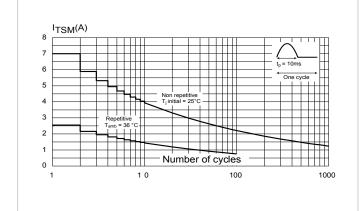


Figure 10. Non-repetitive surge peak on-state current for sinusoidal pulse (t_p < 10 ms)

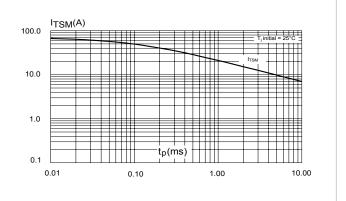
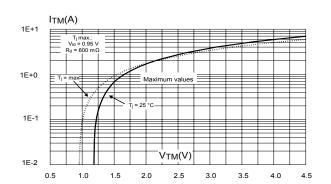


Figure 11. On-state characteristics (maximum values)



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TO-92 package information

- Lead free plating + halogen-free molding resin
- Epoxy meets UL94, V0

Figure 12. TO-92 package outline

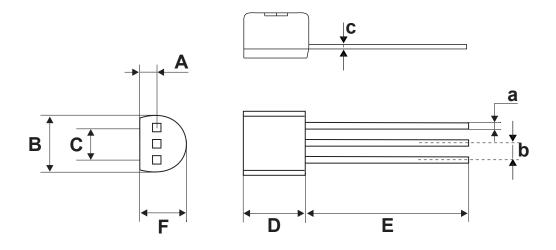


Table 5. TO-92 package mechanical data

				Dimensions			
Ref.	Millimeters				Inches ⁽¹⁾	Inches ⁽¹⁾	
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α		1.35			0.0531		
В			4.70			0.1850	
С		2.54			0.1000		
D	4.40			0.1732			
Е	12.70			0.5000			
F			3.70			0.1457	
а			0.50			0.0197	
b		1.27			0.0500		
С			0.48			0.0189	

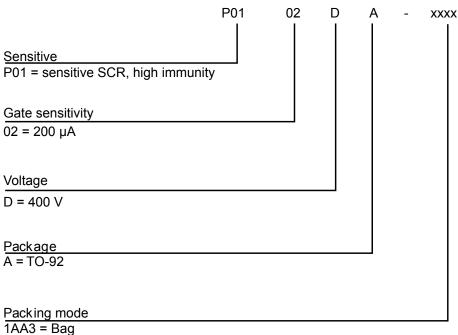
^{1.} Inches dimensions given for information

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Ordering information

Figure 13. Ordering information scheme



2AL3 = Ammopack

5AL3 = Tape and reel 13 inch

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
P0102DA 1AA3				2500	Bag
P0102DA 2AL3	P0102 DA	TO-92	0.22 g	2000	AMMOPACK not in dry bag
P0102DA 5AL3				2000	Tape and reel 13"

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Revision history

Table 7. Document revision history

Date	Revision	Changes	
14-Oct-2019	1	Initial release.	
18-May-2020	2	Updated Section Cover image.	

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